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## SANYO Semiconductors DATA SHEET

# FSS264 — N-Channel Silicon MOSFET General-Purpose Switching Device Applications

### Features

- Low ON-resistance.
- 4V drive.

### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		100	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±20	V
Drain Current (DC)	I <sub>D</sub>		4	A
Drain Current (PW≤10s)	I <sub>D</sub>	Duty cycle≤1%	5	A
Drain Current (PW≤10μs)	I <sub>DP</sub>	Duty cycle≤1%	16	A
Allowable Power Dissipation	P <sub>D</sub>	Mounted on a ceramic board (1200mm²×0.8mm) PW≤10s	2.4	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V	100			V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =2A	3.0	5.5		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)1</sub>	I <sub>D</sub> =2A, V <sub>GS</sub> =10V		65	85	mΩ
	R <sub>DS(on)2</sub>	I <sub>D</sub> =2A, V <sub>GS</sub> =4V		80	112	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =20V, f=1MHz		1560		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =20V, f=1MHz		130		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	V <sub>DS</sub> =20V, f=1MHz		83		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit		16		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		25		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>	See specified Test Circuit		155		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		66		ns

Marking : S264

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**FSS264**

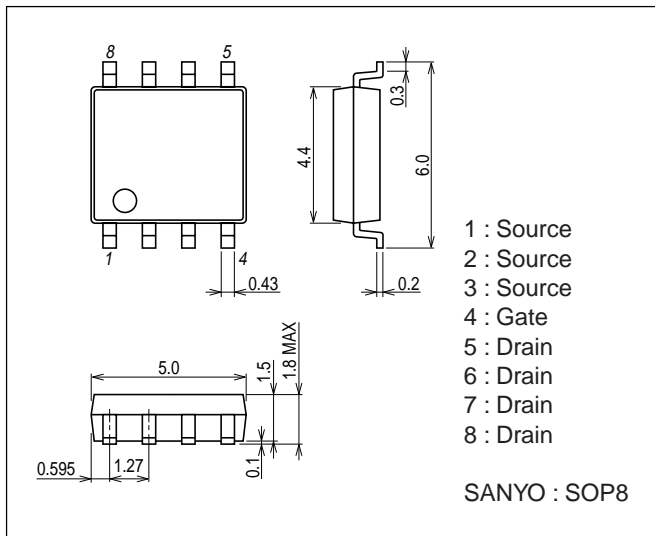
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		34		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		5.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		6		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =4A, V <sub>GS</sub> =0V	0.81		1.2	V

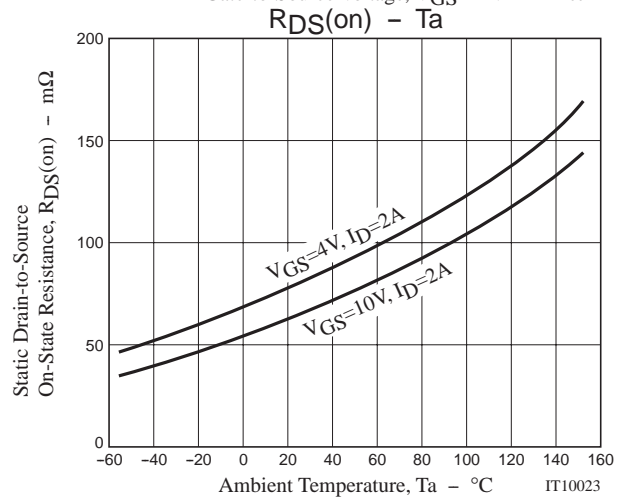
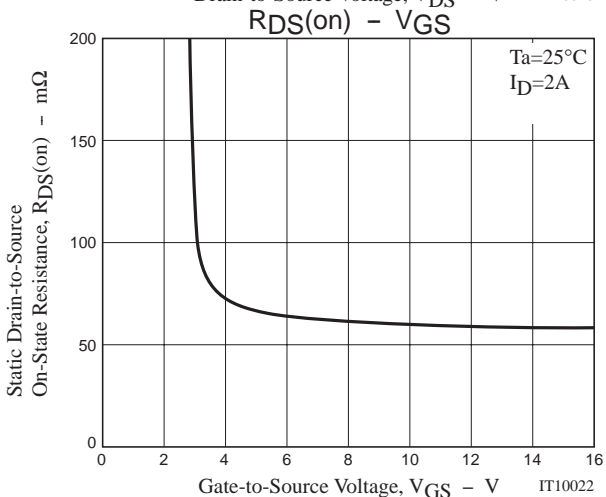
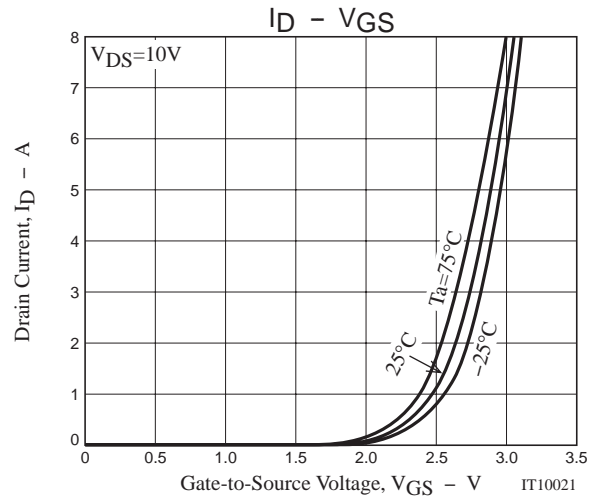
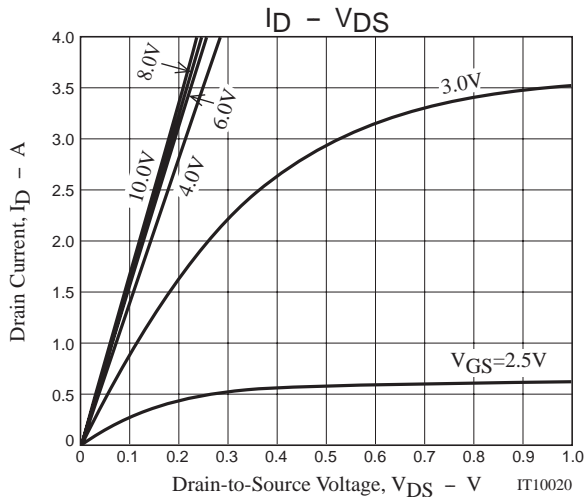
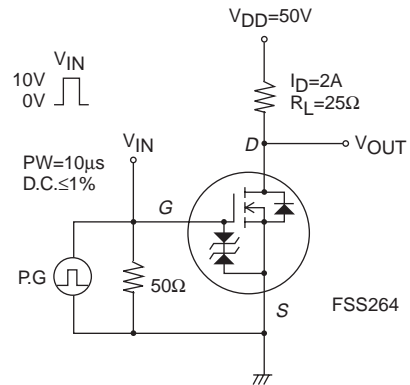
**Package Dimensions**

unit : mm

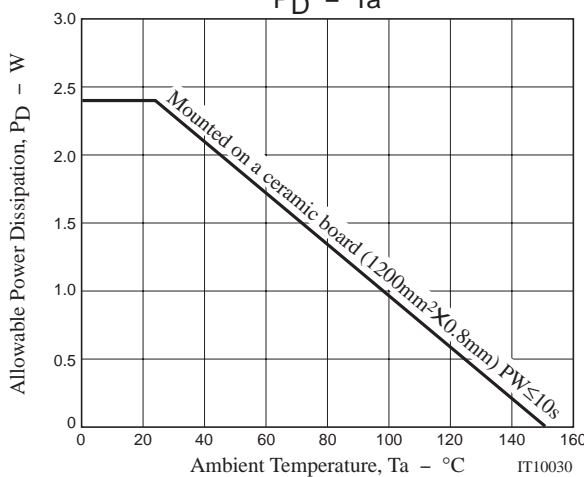
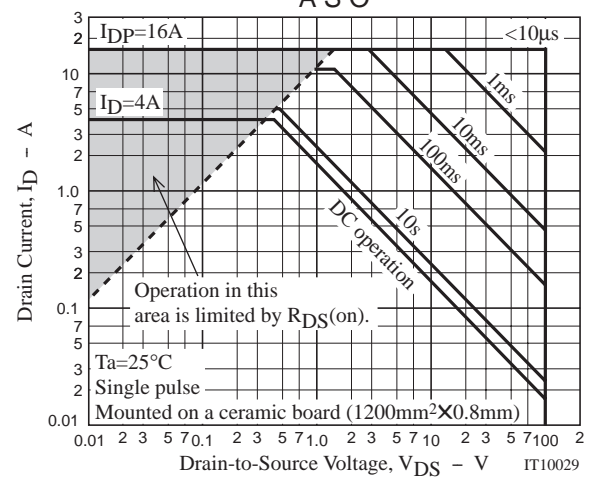
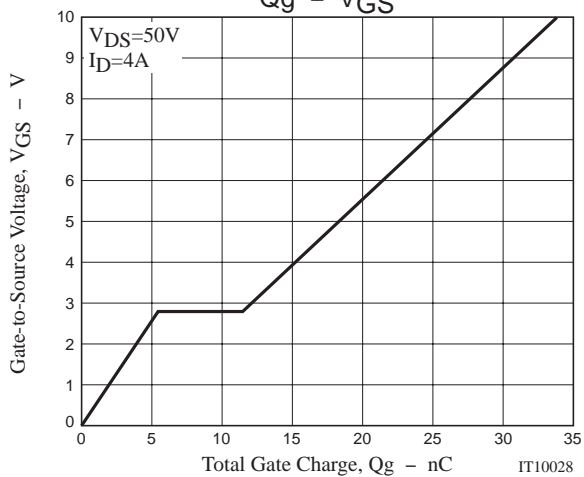
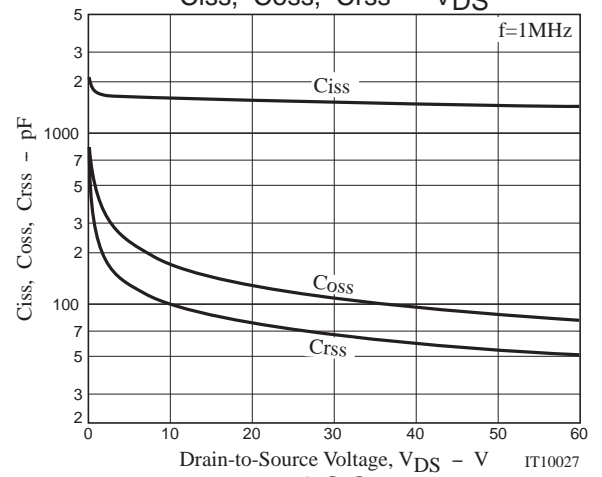
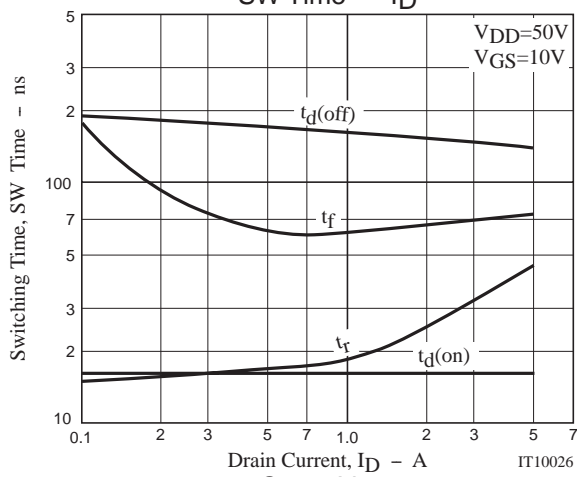
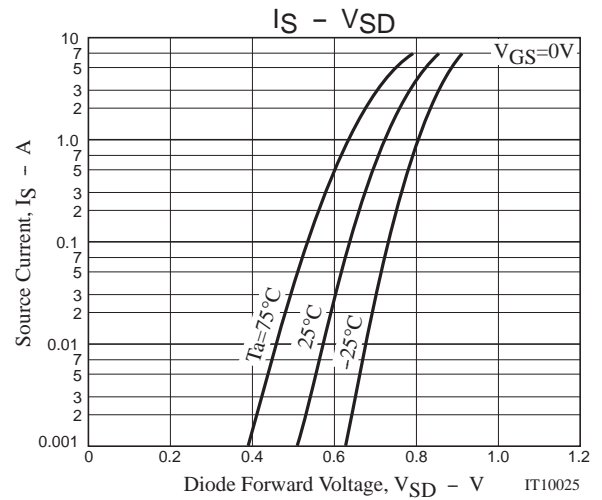
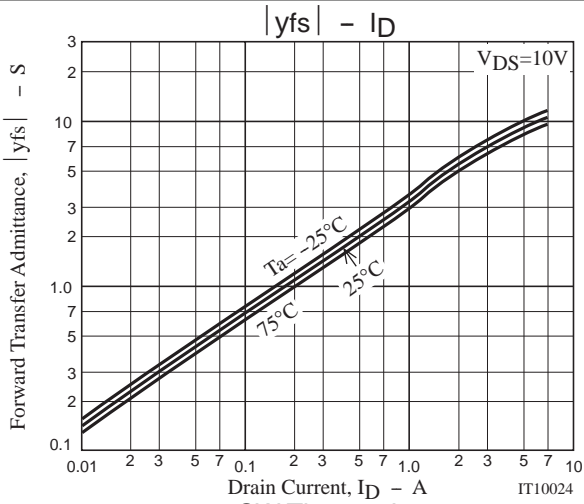
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**Switching Time Test Circuit**



**FSS264**



## FSS264

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Note on usage : Since the FSS264 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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